7F, No. 349, Sec. 2, Renhe Road, Dashi, Taoyuan, Taiwan (R.O.C) 335

Cat No.: 7-1S-1000-062

Revision: 1

AllnGaP LED DICE

Part NO.: AOC-1090xC Series

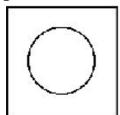
Features

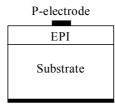
- Orange Color Emission
- Excellent performance and high efficiency
- Great reliability even in harsh environment

Description

AOC-109OxC series is a orange color emitting AlInGaP LED grown by MOCVD technique. Its structure enables enhanced quantum efficiency and therefore a greater light intensity. This device is designed to suit the growing demand in the compact size electronic goods.

Chip Dimensions





Chip Size: 7.7mil×7.7mil±0.5mil Bonding Pad: \phi3.8mil±0.3mil Chip Thickness: 6.5mil±1.0mil

N-electrode

Specification and Optical Characteristics

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Measuring Item	Symbol	Condition	Min	Тур	Max	Unit
Forward Voltage	V_{F}	I _F =20mA	1.70 -		2.30	V
Reverse Current	Ir	V _R =-5V	-	-	1.0	$\mu \mathbf{A}$
Dominant Wavelength	λd	I _F =20mA	600 - 6		620	nm
Max. Junction Temperature	T_{max}	-	≤ 115≤ 30			$^{\circ}\!\mathbb{C}$
Max. DC forward current	I_{f}	Ta = 25°C				mA
Max. pulse forward current	T	Ta = 25°C		≤ 60		mA
(Pulse width 0.1 msec, frequency=1 kHz.)	$ m I_{fm}$	1a – 25 C		≥ 00		
Storago tomporaturo	T_{stg}	Chip on tape	0 ~ 40			$^{\circ}$ C
Storage temperature		Only chip				

Available Dominate Wavelength and Iv Matrix

	Part No.	Wavelength	≥ 100	≥ 110	≥ 120	≥ 130	≥ 140	≥ 150	≥ 160	≥ 170	≥ 180
	rait No.	Range	mcd								
	109 OSC	$600\sim610\;nm$	-	-	-	-	-	-	-	-	-
	109 OLC	$610\sim620\;nm$	-	-	-	L	M	N	О	-	-

Not:

- 1. All measurements are done with AOC's standard testing equipment.
- 2. Luminance intensity is measured on bare chip.
- 3. Above contents are subject to change without notice.
- 4. Special requests are also welcome, please contact AOC's sale representative for any request.

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